FAST PRODUCTS



DATA SHEET

Product specification

1994 Dec 05

IC15 Data Handbook

Philips Semiconductors





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74F373/74F374

74F373 Octal transparent latch (3-State) 74F374 Octal D-type flip-flop (3-State)

FEATURES

- 8-bit transparent latch 74F373
- 8-bit positive edge triggered register 74F374
- 3-State outputs glitch free during power-up and power-down
- Common 3-State output register
- Independent register and 3-State buffer operation
- SSOP Type II Package

DESCRIPTION

The 74F373 is an octal transparent latch coupled to eight 3-State output devices. The two sections of the device are controlled independently by enable (E) and output enable (\overline{OE}) control gates.

The data on the D inputs is transferred to the latch outputs when the enable (E) input is high. The latch remains transparent to the data input while E is high, and stores the data that is present one setup time before the high-to-low enable transition.

The 3-State output buffers are designed to drive heavily loaded 3-State buses, MOS memories, or MOS microprocessors.

The active low output enable (\overline{OE}) controls all eight 3-State buffers independent of the latch operation. When \overline{OE} is low, latched or transparent data appears at the output.

When OE is high, the outputs are in high impedance "off" state, which means they will neither drive nor load the bus.

The 74F374 is an 8-bit edge triggered register coupled to eight 3-State output buffers. The two sections of the device are controlled independently by clock (CP) and output enable (OE) control gates.

The register is fully edge triggered. The state of the D input, one setup time before the low-to-high clock transition is transferred to the corresponding flip-flop's Q output.

The 3-State output buffers are designed to drive heavily loaded 3-State buses, MOS memories, or MOS microprocessors.

The active low output enable (\overline{OE}) controls all eight 3-State buffers independent of the register operation. When \overline{OE} is low, the data in the register appears at the outputs. When \overline{OE} is high, the outputs are in high impedance "off" state, which means they will neither drive nor load the bus.

ТҮРЕ	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)		
74F373	4.5ns	35mA		

TYPE	TYPETYPICAL fmax74F374165MHz	TYPICAL SUPPLY CURRENT (TOTAL)
74F374	165MHz	55mA

ORDERING INFORMATION

	ORDER CODE	
DESCRIPTION	COMMERCIAL RANGE V_{CC} = 5V ±10%, T _{amb} = 0°C to +70°C	PKG DWG #
20-pin plastic DIP	N74F373N, N74F374N	SOT146-1
20-pin plastic SOL	N74F373D, N74F374D	SOT163-1
20-pin plastic SSOP type II	N74F373DB, N74374DB	SOT399-1

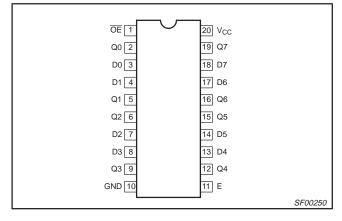
INPUT AND OUTPUT LOADING AND FAN OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
D0 - D7	Data inputs	1.0/1.0	20µA/0.6mA
E (74F373)	Enable input (active high)	1.0/1.0	20µA/0.6mA
OE	Output enable inputs (active low)	1.0/1.0	20µA/0.6mA
CP (74F374)	Clock pulse input (active rising edge)	1.0/1.0	20µA/0.6mA
Q0 - Q7	3-State outputs	150/40	3.0mA/24mA

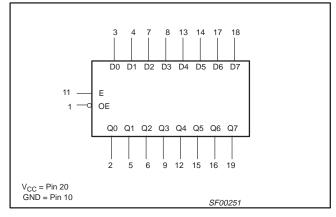
NOTE: One (1.0) FAST unit load is defined as: 20µA in the high state and 0.6mA in the low state.

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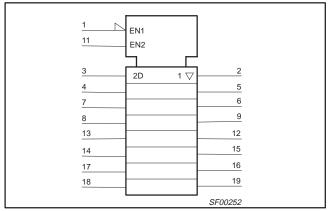
PIN CONFIGURATION – 74F373



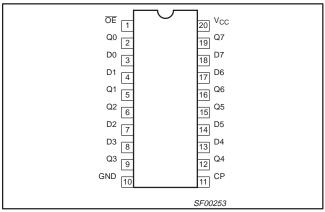
LOGIC SYMBOL – 74F373



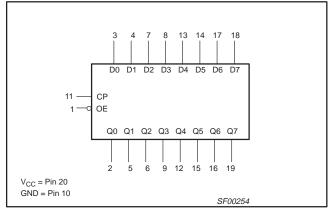
IEC/IEEE SYMBOL - 74F373



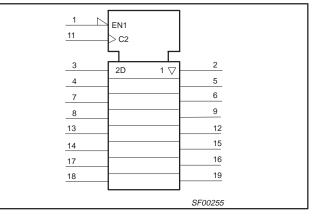
PIN CONFIGURATION - 74F374



IEC/IEE SYMBOL – 74F374

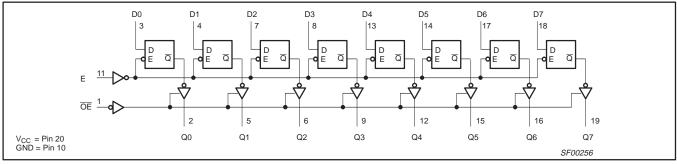


IEC/IEEE SYMBOL – 74F374

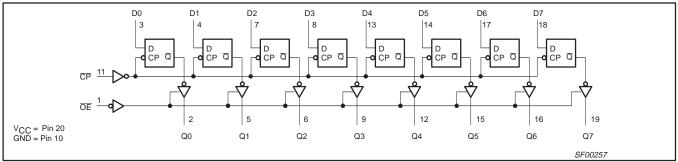


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LOGIC DIAGRAM FOR 74F373



LOGIC DIAGRAM FOR 74F374



FUNCTION TABLE FOR 74F373

	INPUTS		INTERNAL	OUTPUTS	OPERATING MODE
OE	E	Dn	REGISTER	Q0 - Q7	OPERATING MODE
L	Н	L	L	L	Enable and read register
L	Н	Н	Н	Н	Enable and read register
L	\downarrow	I	L	L	Lateb and read register
L	\downarrow	h	н	н	Latch and read register
L	L	Х	NC	NC	Hold
Н	L	Х	NC	Z	
Н	Н	Dn	Dn	Z	Disable outputs

NOTES:

H = High-voltage level

High state must be present one setup time before the high-to-low enable transition h =

L Low-voltage level =

Low state must be present one setup time before the high-to-low enable transition L =

NC= No change

 $X = Z = \downarrow =$ Don't care

High impedance "off" state

High-to-low enable transition

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FUNCTION TABLE FOR 74F374

	INPUTS		INTERNAL	OUTPUTS	OPERATING MODE
OE	СР	Dn	REGISTER	Q0 - Q7	OPERATING MODE
L	↑	I	L	L	Load and read register
L	↑	h	Н	Н	
L	\$	Х	NC	NC	Hold
Н	\$	Х	NC	Z	
Н	↑	Dn	Dn	Z	Disable outputs

NOTES:

H = High-voltage level

h = High state must be present one setup time before the low-to-high clock transition

L = Low-voltage level

I = Low state must be present one setup time before the low-to-high clock transition

NC= No change

X = Don't care

Z = High impedance "off" state

 \uparrow = Low-to-high clock transition

 \uparrow = Not low-to-high clock transition

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	-30 to +5	mA
V _{OUT}	Voltage applied to output in high output state	-0.5 to V _{CC}	V
I _{OUT}	Current applied to output in low output state	48	mA
T _{amb}	Operating free air temperature range	0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		UNIT			
STMBOL		MIN	NOM	MAX	UNIT	
V _{CC}	Supply voltage	4.5	5.0	5.5	V	
V _{IH}	High-level input voltage	2.0			V	
V _{IL}	Low-level input voltage			0.8	V	
l _{lk}	Input clamp current			-18	mA	
I _{ОН}	High-level output current			-3	mA	
I _{OL}	Low-level output current			24	mA	
T _{amb}	Operating free air temperature range	0		+70	°C	

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DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

CVMPOI	DADAMETED		TEST					
SYMBOL	PARAMETER		CONDITIONS ¹	MIN	TYP ²	MAX	UNIT	
			$V_{CC} = MIN, V_{IL} = MAX,$	$\pm 10\% V_{CC}$	2.4			V
V _{OH}	High-level output voltage		V _{IH} = MIN, I _{OH} = MAX	±5%V _{CC}	2.7	3.4		V
Ve			V _{CC} = MIN, V _{IL} = MAX,	±10%V _{CC}		0.35	0.50	V
V _{OL}	Low-level output voltage		V _{IH} = MIN, I _{OL} = MAX	±5%V _{CC}		0.35	0.50	V
V _{IK}	Input clamp voltage	$V_{CC} = MIN, I_I = I_{IK}$	-		-0.73	-1.2	V	
lj –	Input current at maximum input voltage		V _{CC} = MAX, V _I = 7.0V			100	μΑ	
I _{IH}	High-level input current		V _{CC} = MAX, V _I = 2.7V			20	μA	
IIL	Low-level input current		$V_{CC} = MAX, V_I = 0.5V$			-0.6	mA	
I _{OZH}	Off-state output current, high-level voltage ap	plied	$V_{CC} = MAX, V_O = 2.7V$				50	μA
I _{OZL}	Off-state output current, low-level voltage app	olied	$V_{CC} = MAX, V_O = 0.5V$			-50	μΑ	
I _{OS}	Short-circuit output current ³	V _{CC} = MAX	-60		-150	mA		
	Supply surrent (total)	74F373				35	60	mA
Icc	Supply current (total)	V _{CC} = MAX		57	86	mA		

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

2. All typical values are at V_{CC} = 5V, T_{amb} = 25 ^{\circ}C.

3. Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

AC ELECTRICAL CHARACTERISTICS

				LIMITS					
SYMBOL	DADAMETED	TEST		_{mb} = +25 _{CC} = +5.0		$T_{amb} = 0^{\circ}C$	UNIT		
STWBUL	PARAMETER	PARAMETER				= 500 Ω	V _{CC} = +5. C _L = 50pF,		UNIT
				MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay Dn to Qn		Waveform 3	3.0 2.0	5.3 3.7	7.0 5.0	3.0 2.0	8.0 6.0	ns
t _{PLH} t _{PHL}	Propagation delay E to Qn	74F373	Waveform 2	5.0 3.0	9.0 4.0	11.5 7.0	5.0 3.0	12.0 8.0	ns
t _{PZH} t _{PZL}	Output enable time to high or low level		Waveform 6 Waveform 7	2.0 2.0	5.0 5.6	11.0 7.5	2.0 2.0	11.5 8.5	ns
t _{PHZ} t _{PLZ}	Output disable time from high or low level		Waveform 6 Waveform 7	2.0 2.0	4.5 3.8	6.5 5.0	2.0 2.0	7.0 6.0	ns
f _{max}	Maximum clock frequency		Waveform 1	150	165		140		ns
t _{PLH} t _{PHL}	Propagation delay CP to Qn	74F374	Waveform 1	3.5 3.5	5.0 5.0	7.5 7.5	3.0 3.0	8.5 8.5	ns
t _{PZH} t _{PZL}	Output enable time to high or low level		Waveform 6 Waveform 7	2.0 2.0	9.0 5.3	11.0 7.5	2.0 2.0	12.0 8.5	ns
t _{PHZ} t _{PLZ}	Output disable time from high or low level		Waveform 6 Waveform 7	2.0 2.0	5.3 4.3	6.0 5.5	2.0 2.0	7.0 6.5	ns

Product specification

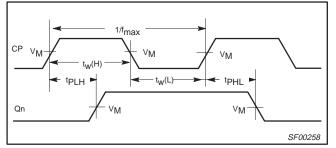
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AC SETUP REQUIREMENTS

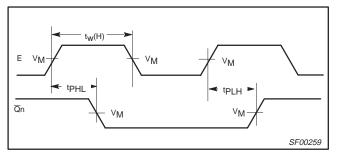
			LIMITS							
SYMBOL	SYMBOL PARAMETER		PARAMETER		TEST CONDITION	v.	_{mb} = +25 _{CC} = +5.0 0pF, R _L :	v	T _{amb} = 0°C V _{CC} = +5. C _L = 50pF,	UNIT
				MIN	TYP	MAX	MIN	MAX		
t _{su} (H) t _{su} (L)	Setup time, high or low level Dn to E		Waveform 4	0 1.0			0 1.0		ns	
t _h (H) t _h (L)	Hold time, high or low level Dn to E	74F373	Waveform 4	3.0 3.0			3.0 3.0		ns	
t _w (H)	E Pulse width, high		Waveform 1	3.5			4.0		ns	
t _{su} (H) t _{su} (L)	Setup time, high or low level Dn to CP		Waveform 5	2.0 2.0			2.0 2.0		ns	
t _h (H) t _h (L)	Hold time, high or low level Dn to CP	74F374	Waveform 5	0 0			0 0		ns	
t _w (H) t _w (L)	CP Pulse width, high or low		Waveform 5	3.5 4.0			3.5 4.0		ns	

AC WAVEFORMS

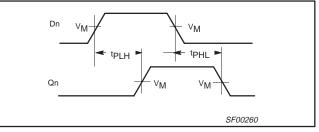
For all waveforms, $V_{\rm M}$ = 1.5V. The shaded areas indicate when the input is permitted to change for predictable output performance.



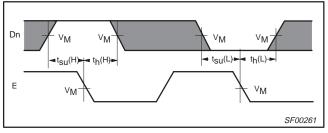
Waveform 1. Propagation delay for clock input to output, clock pulse widths, and maximum clock frequency



Waveform 2. Propagation delay for enable to output and enable pulse width



Waveform 3. Propagation delay for data to output



Waveform 4. Data setup time and hold times

SF00265

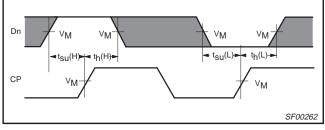
Latch/flip-flop

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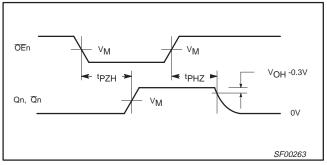
AC WAVEFORMS (Continued)

For all waveforms, $V_{M} = 1.5V$.

The shaded areas indicate when the input is permitted to change for predictable output performance.

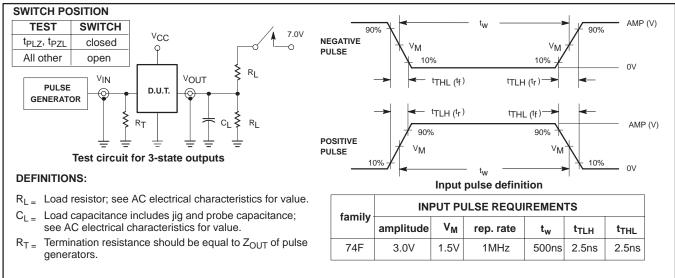


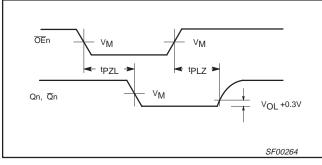
Waveform 5. Data setup time and hold times



Waveform 6. 3-State output enable time to high level and output disable time from high level

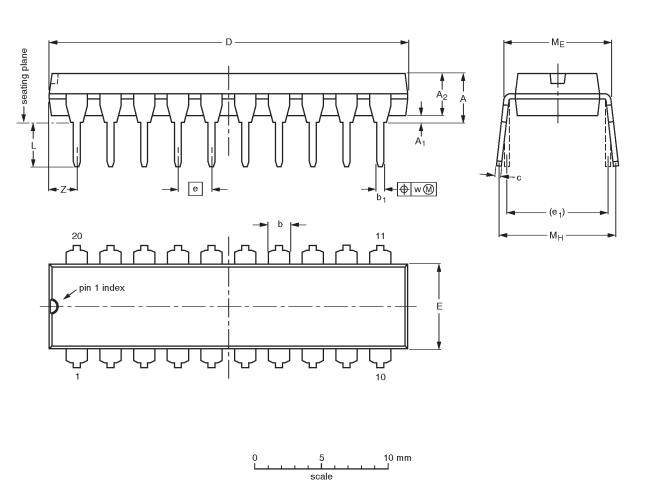
TEST CIRCUIT AND WAVEFORMS





Waveform 7. 3-State output enable time to low level and output disable time from low level

DIP20: plastic dual in-line package; 20 leads (300 mil)



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	Е ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT146-1			SC603			-92-11-17 95-05-24

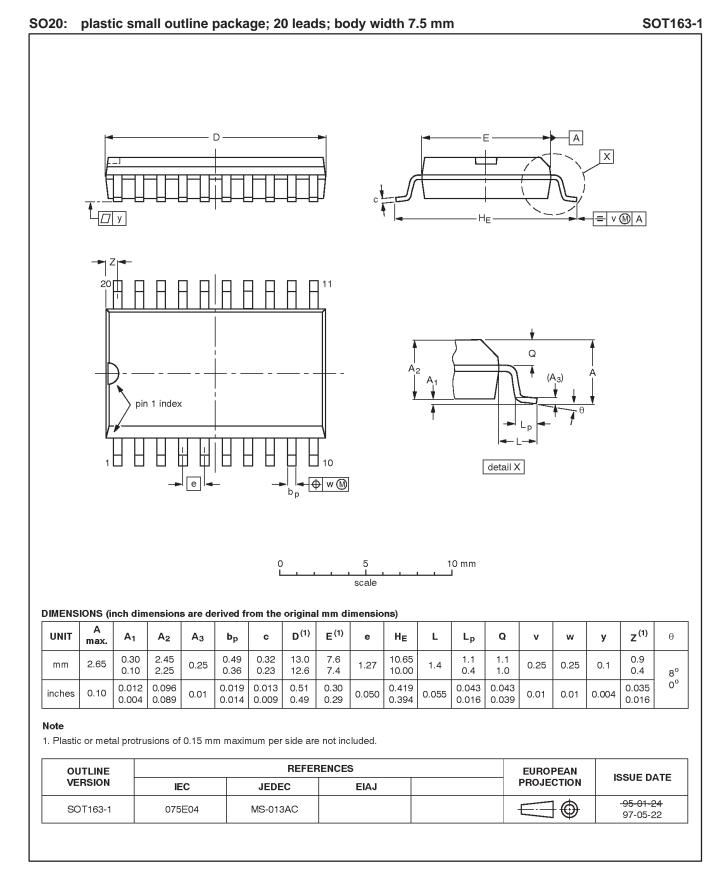
Product specification

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NOTES

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DEFINITIONS				
Data Sheet Identification	Product Status Definition			
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.		
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
Product Specification Full Production		This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.		

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Date of release: July 1994

9397-750-05119

Document order number: